

## Thermoelectric effect in superconducting nanostructures

V. L. Gurevich,<sup>1</sup> V. I. Kozub,<sup>1</sup> and A. L. Shelankov<sup>1,2</sup><sup>1</sup>A. F. Ioannissian Physico-Technical Institute, 19021 St. Petersburg, Russia.<sup>2</sup>Department of Physics, Umeå University, SE-901 87 Umeå

(Dated: 19 July 2005)

We study thermoelectric effects in superconducting nanobridges and demonstrate that the magnitude of these effects can be comparable or even larger than that for a macroscopic circuit. It is shown that a large gradient of the electron temperature can be realistically created on nanoscale and masking effects of spurious magnetic fields are minimal in nanostructures. For these reasons nanodevices are favorable for studying the thermoelectric effect in superconductors.

PACS numbers: 74.25.Fy, 74.78.Na, 73.63.Rt

## I. INTRODUCTION

The discrepancy between the theory and experiment concerning the thermoelectric phenomena is a long standing problem in physics of superconductors. The thermoelectric phenomena in the superconducting state were first discussed by Ginzburg as early as 1944. In the presence of a temperature gradient, there appears in a superconductor a normal current of the form given by

$$\mathbf{j}_T = -\sigma_T \nabla T \quad (1.1)$$

where  $\sigma_T$  is the corresponding transport coefficient. In the bulk of a homogeneous isotropic superconductor the total electric current must vanish, and as was pointed out by Ginzburg<sup>1</sup>, the normal current is offset by a supercurrent  $\mathbf{j}_S$  so that the total current in the bulk

$$\mathbf{j}_T + \mathbf{j}_S = 0: \quad (1.2)$$

This makes impossible standard studies of the thermoelectric effect in a homogeneous isotropic superconductor. Ginzburg considered also simply-connected anisotropic or inhomogeneous superconductors as systems where it is possible to observe thermoelectric phenomena by measuring the magnetic field generated by a temperature gradient.

Theory of the effect was further developed in 1970s<sup>2</sup>. It was noted in particular that the offset supercurrent is related to a difference of the order parameter phases within the simply-connected superconductor. This phase difference can be measured either in superconducting interferometer or in the loop formed by different superconductors where a magnetic flux is generated in the presence of a temperature difference. It stimulated experimental study of the effect. Although the first experiment performed by Zavaritsky<sup>3</sup> is in a rather good agreement with the existing theory, further experiments (see e.g.<sup>4,5</sup>) exhibit temperature-dependent magnetic fluxes of order of magnitude larger than is predicted by the theory<sup>2</sup>. A possibility to observe large thermoelectric fluxes is discussed in<sup>6</sup> and is related to the phonon drag effect near the contact of the two superconductors with different values of superconducting gap. However, the predicted en-

hancement factor, the ratio of the Fermi energy and Debye energy, is not big enough to bridge the gap between the experiment<sup>4,5</sup> and the theory.

From the experimental point, the main difficulty is due to the fact that the thermoelectric effect is small at low temperatures, and one needs to single it out from various masking effects. The most obvious one is related to the temperature dependence of the magnetic field penetration length<sup>7,8</sup>. As a result, in the presence of a background magnetic field, the magnetic field within the superconductor is temperature dependent. This can mask the genuine thermoelectric effect. It is important to note that later on it was shown that the co-existence of a temperature gradient and a supercurrent leads to variation of the gauge invariant scalar potential related to an imbalance between the electron-like and hole-like quasiparticle branches<sup>9,10,11,12</sup>. In contrast to the thermoelectric flux, the experimental studies of this effect were in agreement with the theory<sup>12</sup>.

The goal of the present paper is to discuss the geometry of experiment where the thermoelectric effect is particularly large while the masking effects are significantly suppressed. Therefore one can hope that it will guarantee unambiguous measurements of the thermoelectric effect. With this purpose in mind we will consider thermoelectric effect in superconducting circuit containing a point contact.

Thermoelectric phenomena in superconducting nanostructures have some unique specific features that (i) are favorable from the experimental point of view and (ii) require certain revision of the existing theory. Experimentally, the advantage is that one is able to create very large temperature gradients so that the intrinsic thermoelectric current becomes larger and easier to observe. We note such a favorable possibility can be realized only in the systems where the electrons can be heated as compared to the lattice. Indeed, a realistic nanostructures imply a presence of an (insulating) substrate it is deposited on, and thus large gradients of the lattice temperature can not be achieved because of the phonon heat conductance in the substrate. In contrast, the electron temperature, according to the Wiedemann-Franz law, behaves in the same way as the electrostatic potential. A detailed dis-

cussion demonstrating possibility to obtain large gradients of electron temperature in metal nanostructures is given in the Appendices. Most important, the parasitic effects due to the trapped magnetic field are much less pronounced in small size structures.

On the theoretical side, a revision is needed because the earlier theories have considered bulk samples. Their sizes have been assumed to be much larger than the characteristic lengths such as the London penetration length and the length at which the onset supercurrent is generated. When applied to bulk samples, there is no need to specify and go into detail of the mechanism by which the normal thermoelectric current is converted into the onset supercurrent. This approach is valid provided the sample size much exceeds the size of the region where the normal thermoelectric current is converted into the onset supercurrent. It is well known from the microscopic theory that the conversion occurs as a result of branch-mixing scattering processes, where electron-like excitations are scattered to the hole branch of the excitation spectrum and vice versa. Microscopic mechanism of the branch-mixing is known to be inelastic scattering, impurity scattering in the case of anisotropic superconductors, and Andreev reflection if inhomogeneity of the order parameter gap is present. If the bulk scattering is the dominant mechanism, the conversion takes place along the branch-mixing diffusion length  $L_b$ ,  $L_b = \frac{D}{D_b}$ ,  $D$  and  $D_b$  being the diffusion constant and the branch-mixing relaxation time, respectively. For a nanostructure of the size comparable with the branch-mixing length, the standard theory of the thermoelectric phenomena (that assumes local compensation of the thermoelectric current) is not applicable. Indeed, in this case the normal thermoelectric current can be onset also by a normal diffusion current rather than by a supercurrent<sup>13</sup>.

In addition to kinetics, there are important differences in electrodynamics of superconducting nanostructures. In particular, it is related to the so-called kinetic inductance  $L_k$

$$L_k = \frac{L_L^2}{S} : \quad (1.3)$$

Here  $L_L$  is the London penetration length,  $L$  is the circuit length while  $S$  is the circuit cross-section.  $L_k$  is inversely proportional to  $S$  and may be larger than the magnetic inductance of the thermoelectric loop for very small values of  $S$ . In this case, the local compensation of the current in Eq. (1.2) turns out to be energetically unfavorable and the electrodynamical part of the theory requires a revision too.

In what follows we will develop a theory of thermoelectric effect in superconducting nanostructures. It will include the above kinetic and electrodynamical effects.

## II. CHARGE IMBALANCE DISTRIBUTION

Consider two superconducting leads (banks) connected by a narrow wire of the length  $L$  and cross-section  $S$ ; the transverse sizes of the wire are assumed to be much smaller than the London penetration length  $L_L$ . In this case, the current is distributed homogeneously across the wire cross-section, and the problem is one dimensional. Denote  $x$  the coordinate along the wire and choose the origin in the middle of the wire. We analyse a diffusive wire and assume that the temperature varies linearly along the wire between, its values at the banks being  $T_L$  and  $T_R$ . Note that the thermoelectric current is considered a constant equal to  $\frac{1}{2} r T$  in the wire and zero in the banks. This assumption holds for 3D structures where both the temperature gradient and electric current density quickly decays within the contact. Naturally, we assume that the thickness of the wire is much smaller than the thicknesses of the banks.

First, we briefly overview the well-known physics of branch imbalance in superconductors. The total electric current density,  $j = j_s + j_n$ , is a sum of the supercurrent,  $j_s$ , and normal,  $j_n$ , components. The supercurrent reads

$$j_s = \frac{c^2}{4 e L} p_s \quad (2.1)$$

where  $p_s$  is the superfluid momentum,

$$p_s = \frac{\hbar}{2} r \frac{e}{c} A ; \quad (2.2)$$

and  $A$  being the phase of the order parameter and the vector potential, respectively.

The normal current,

$$j_n = j_T + j_D ; \quad (2.3)$$

is a sum of the thermoelectric current  $j_T = \frac{1}{2} r T$ , and the diffusion component,  $j_D = \frac{1}{2} r$ , related to the branch imbalance specified by the gauge invariant potential  $\phi$  as,

$$j_D = \frac{\hbar}{2 e} \nabla \phi ; \quad (2.4)$$

$\phi$  being the scalar potential. In the vicinity of the critical temperature, the diffusion current is proportional to the normal state conductance  $G_N$ .

### A. Diffusion limit

The potentials  $p_s$  and  $\phi$  are found from the continuity equation  $\text{div} j = 0$ , and the equation which describes transformation of the normal current into supercurrent that results in the following equation for  $\phi$  in the wire (see, for instance, Ref. 14)

$$r^2 \frac{\nabla^2 \phi}{L_b^2} = 0 \quad (2.5)$$

where  $\tau_b$  is the branch imbalance relaxation time while  $L_b = D_b$  is the branch imbalance relaxation length<sup>15</sup>. If the banks are made of superconductors with different gap values, Eq. (2.5) requires a boundary condition<sup>16</sup> to account for the Andreev reflection at the interface. The latter plays the role of a surface mechanism of branch-mixing.

The boundary condition to Eq. (2.5) rather generally takes the form<sup>16</sup>

$$\frac{1}{L_b} \frac{j_n}{x=L=2} = \frac{1}{L_b} \frac{j_n}{x=L=2} \quad (2.6)$$

where  $j_n$  is the  $x$  component of the normal charge current in Eq. (2.3), and  $L_b$  is an effective relaxation length controlled by the Andreev reflection at the wire-bank interface as well as the branch-mixing rate in the banks.

Solution to Eq. (2.5) with the boundary condition Eq. (2.6) reads

$$j(x) = j_0 \frac{\sinh \frac{x}{2L_b}}{\sinh \frac{L}{2L_b}}$$

where

$$j_0 = \frac{1}{\frac{1}{L_b} + \frac{1}{2L_b} \coth \frac{L}{2L_b}} j_T \quad (2.7)$$

The condensate momentum  $p_s$  and the supercurrent  $j_s$  is found from the continuity equation  $\text{div} j = 0$ , that is  $j(x) = j_0$ , where  $j_0$  is a constant. From the condition  $j_s(x) + j_n(x) = j_0$  where  $j_n(x) = j_T \frac{x}{L}$ , the distribution of the supercurrent is given by the following expression

$$j_s(x) = j_0 \left( 1 - \frac{1}{\frac{2L_b}{L} + \coth \frac{L}{2L_b}} \frac{\cosh \frac{x}{2L_b}}{\sinh \frac{L}{2L_b}} \right) \quad (2.8)$$

If there is no electrical connection between the banks other than the wire, the total current must be zero,  $j_0 = 0$ . Otherwise, the constant  $j_0$  is found from electrodynamic considerations considered in the next section.

Thus the temperature difference between the banks leads to a creation of a potential difference equal to  $\Delta T$  with  $\Delta T$  in Eq. (2.7). The potential difference can be measured, for instance, as described in Ref. 17. Note that this effect is of the nature considered by Artemenko and Volkov<sup>13</sup>. However, they treated a macroscopic circuit with a size  $L$  much larger than  $L_b$  so that the potential difference was concentrated near the interface region thus involving only a small part of the total temperature difference  $\Delta T = L \Delta T$ . As a result, their estimate for "thermoelectric" potential difference is

$$\Delta T = \frac{L_b}{L} \Delta T \quad (2.9)$$

for a macroscopic wire, the length of which  $L$  exceeds the microscopic scales  $L_b$  and  $L_b$ .

In the present paper, we are interested in the opposite limit of a short wire,  $L < L_b$ . It follows from Eq. (2.7) that the potential difference in this limit is

$$\Delta T = \frac{j_T}{\frac{1}{L_b} + \frac{1}{L}} \quad (2.10)$$

For a short enough wire,  $L \ll L_b$ , we obtain

$$\Delta T = T \quad (2.11)$$

In this case of a short superconducting wire, the thermoelectric potential difference is of the order of that in the normal state.

In a short wire, the supercurrent Eq. (2.8) is homogeneous,

$$j_s = j_0 = j \frac{L}{L + L_b} \quad (2.12)$$

where as before  $j_0$  is the total electric current through the wire.

## B. Ballistic bridge

When we studied the branch imbalance in the previous section, for the simplicity we have exploited the diffusive approximation. However, the largest values of  $j_T$  correspond to the largest values of the mean quasiparticle free path within the wire (leading to larger  $\Delta T$ ). So one expects the largest effect for a ballistic bridge. In this case one can estimate the quasiparticle thermoelectric current with the help of a procedure similar to the one used in Ref. 18. Namely, one has in mind that the quasiparticle distribution function within the ballistic bridge is formed by the quasiparticles entering the bridge from the banks. One also notes that the distribution function is constant along the quasiparticle trajectory while the quasi-equilibrium distribution functions of the left and right banks correspond to different temperatures ( $T_L$  and  $T_R$ , respectively). Thus for the quasiparticle distribution function,  $F_B$ , within the bridge one has

$$F_B = v_x \frac{1}{v_F} F(T_L) + v_x \frac{1}{v_F} F(T_R) \quad (2.13)$$

Here  $v_x$  is the component of the electron velocity along the bridge direction, and  $F(T_{L,R})$  stands for the equilibrium distribution function corresponding to the temperature  $T_{L,R}$ . We have taken into account that the (group) quasiparticle velocity differs from the "bare" electron velocity by a factor  $\frac{v_x}{v_F} = \frac{v_x}{v_F} \frac{E_F}{E_F + \Delta} \approx \frac{v_x}{v_F} \frac{E_F}{E_F + \Delta}$ ,  $v_F$  being the kinetic energy counted from the Fermi energy, and  $\Delta$  being the superconductor energy gap. Given the distribution function in Eq. (2.13), the normal thermoelectric current reads

$$j_T = e \sum_p v_x F_B$$

As usual in the theory of thermoelectric phenomena, the contributions of electrons and holes to the current tend to cancel each other, and the net effect is sensitive to details of the band structure and to the energy dependence of the density of states, in particular. At temperatures  $T \ll T_c$ , the order of magnitude of the thermoelectric current can be estimated as

$$j_T \approx e v_F n \frac{(T_L^2 - T_R^2)}{\epsilon_F^2} : \quad (2.14)$$

where  $v_F$  and  $\epsilon_F$  are the Fermi velocity and energy, respectively, and  $n$  is the electron density. For a rough estimate, assume that the temperature difference is comparable to  $T_c$ . In this case,

$$j_T \approx e n v_F \frac{T_c^2}{\epsilon_F} \quad (2.15)$$

Thus a presence of a temperature drop at the contact between two superconducting banks leads to formation of the thermoelectric current through the nanobridge the order of magnitude of which can be evaluated according to Eq. (2.15). The total thermoelectric current,  $I_T$ , is found by the multiplication of the current density  $j_T$  and the bridge cross-section  $S$ ,  $I_T = j_T S$ :

### III. THERMOELECTRIC FLUX

As we have discussed above, we study a nanostructure that consists of a superconducting bridge with a thickness and a width smaller than the London penetration depth  $\lambda_L$ . The bridge joins two banks made of the same superconductor (with a critical temperature  $T_{c1}$  and a thickness smaller than  $\lambda_L$ ). By means of a point-like heating, using e.g. N-S tunnel junction (see Appendix), the banks are kept at different temperatures. We assume that the bridge region carrying thermoelectric current  $I_T$  is short-circuited by superconducting branch with sizes larger than  $\lambda_L$  forming a loop of the linear size  $L$ . The behaviour of the system is different for the two limiting cases: a)  $L > L_b$ ; b)  $L < L_b$ .

We start our analysis with the first one, that is the case when the branch imbalance relaxation length  $L_b$  is much shorter than the size of the system. It can be realized in particular if the near-contact region at least for one of the banks is covered by the superconductor with a larger gap leading to effective imbalance relaxation due to Andreev reflections. If the circuit is simple-connected the thermoelectric current is compensated by the supercurrent created due to the Andreev reflection or bulk mechanisms of the charge imbalance relaxation. Thus the decay of the normal thermoelectric current is locally compensated by supercurrent.

The situation becomes different if the circuit is not simple-connected, i.e., when another branch (made, for instance, of the material with a larger  $T_c$ ) closes the loop. In this case, the net electric current, built of the

normal thermoelectric and superconducting components, through the bridge may be finite for the charge current continuity is maintained by the supercurrent  $I_c$  through the branch closing the loop:  $I_c$  is actually the electric current circulating in the loop, and  $(I_c - I_T)$  is the superconducting component of the net current through the bridge. The circulating current  $I_c$  can be readily evaluated minimizing the total energy  $W$  of the system. The latter is given by the following expression,

$$W = \frac{1}{2} (I_T - I_c)^2 L_k + \frac{1}{2} I_c^2 L : \quad (3.1)$$

The first term originates from the kinetic energy of superconducting electrons in the bridge,  $L_k$  being the well-known kinetic inductance,

$$L_k = \frac{L^2}{S}$$

(where  $L$  and  $S$ , as above, are the bridge length and cross-section, respectively). The second term in Eq. (3.1) is the energy of magnetic field created by the circulating current  $I_c$ , and  $L$  is the inductance of the loop, which is close to the geometrical inductance of the macroscopic branch. Minimizing  $W$  with respect to  $I_c$ , one obtains

$$I_c = I_T \frac{L_k}{L_k + L} \quad (3.2)$$

and, thus the thermoelectric magnetic flux is

$$\Phi_T = I_T \frac{L_k L}{L_k + L} : \quad (3.3)$$

The flux  $\Phi_T$  is controlled by the smaller of the inductances in question.

Note that if  $L_k \ll L$ ;  $\Phi_T$  does not depend on  $L$  and is estimated as

$$\Phi_T = I_T L_k \approx I_T \frac{L^2}{S} : \quad (3.4)$$

In the dirty limit, the penetration depth  $\lambda_L$  is related to its value in the bulk pure material as

$$\frac{\lambda_L^2}{\lambda_0^2} = \frac{1}{1 + \lambda_0^2 / l_e^2}$$

where  $\lambda_0 = \lambda_L = \lambda_0$  is the coherence length, and  $l_e$  is the electron elastic mean free path. As it can be seen, this result coincides with the predictions of the papers<sup>2,4</sup> assuming that the thermoelectric current is almost completely compensated by the supercurrent.

However, the situation is qualitatively different if  $L_k \gg L$ , a condition which can be realistically met for a nanoscale bridge. Indeed, assuming  $L \approx S$  and  $L \approx 10^{-6}$  cm, for  $\lambda_0 \approx 10^{-5}$  cm,  $\lambda_0 \approx 10^{-4}$  cm, one obtains  $L_k \approx 10^{-2}$  cm. This means that the kinetic inductance  $L_k$  may be comparable to the magnetic geometric inductance  $L$  even for a relatively large, nearly macroscopic loop. In this case, the normal thermoelectric current generated by the bridge is non-locally short-circuited by the supercurrent through the macroscopic

branch than being offset locally by the supercurrent. In this limit, one has from Eq. (3.3):

$$T = I_T L; \quad (3.5)$$

Despite the absence of the current cancellation within the bridge, the flux through the loop is  $\Phi_k = L$  times smaller than it has been predicted in earlier papers<sup>2,4</sup>. At the same time, the magnetic field within the structure practically coincides with its value for a normal metal structure. Correspondingly, it can be much larger than for the thermoelectric effect in macroscopic circuits. Indeed, assuming that the inductance  $L$  is of the order of the linear size of the circuit, our estimates for the magnetic field from Eqs. (3.4), and (3.5) are

$$H_T \approx I_T \frac{L_k}{L^2}; \quad L_k \ll L \quad (3.6)$$

and

$$H_T \approx \frac{I_T}{L}; \quad L_k \ll L \quad (3.7)$$

Thus the "thermoelectric" magnetic field is the larger the smaller is  $L$  and is much larger for the regime  $L_k > L$  than for a "macroscopic" considered earlier in<sup>2,4</sup>. We believe that this factor significantly suppresses a possible role of masking effects.

In the limiting case (b), when the charge imbalance length  $L_b$  is much shorter than the size of the system ( $L < L_b$ ), the quasiparticle thermoelectric current is not converted into a supercurrent but short-circuited by the normal current through the closing branch (as it occurs in normal metal thermoelectric circuits). The normal charge current in the loop generates a magnetic flux which in turn generates a circulating supercurrent  $I_c$  in the direction opposite to the normal current. In this case, the energy  $W = I_c^2 L_k = 2 + (I_T - I_b)^2 L = 2$  is built of the supercurrent kinetic energy  $I_c^2 L_k = 2$  and the magnetic energy  $(I_T - I_b)^2 L = 2$ . Minimizing  $W$ ,

$$I_c = I_T \frac{L}{L + L_k};$$

and the total thermoelectric flux,  $\Phi_T = (I_T - I_b)L$ , is again given by Eq. (3.3). Therefore, the thermoelectric flux  $\Phi_T$  is completely controlled by the normal component if  $L_k > L$ .

Let us estimate the largest possible values of  $T$  which can be realized for large  $L$ . We have

$$T \approx I_T \frac{L^2}{S} \quad (3.8)$$

where  $L$  and  $S$  are the bridge length and cross-section respectively.

Correspondingly,

$$T \approx \frac{T_0}{L} \frac{L^2}{S} \quad (3.9)$$

In what follows we will assume that all the sizes of the bridge are of the same order while one should also put  $L_b \approx L$ . Assuming  $T = 10^4$  (T = 1K),  $10^{10} \text{ cm}^2$ ,  $10^{-4} \text{ cm}$  one has  $T \approx 10^3$  K.

For smaller  $L$  the magnetic fluxes are smaller than the above estimate but the magnetic fields are higher.

#### IV. CONCLUSION

In this paper we have analyzed the thermoelectric effects in superconducting nanostructures. When the size of a thermoelectric circuit is less than the branch imbalance length, the very picture of the thermoelectric effects becomes different from that considered earlier for macroscopic systems: rather than being offset locally by the supercurrent, the quasiparticle thermoelectric current is short-circuited nonlocally, by the diffusion current in the branch closing the circuit, similar to the picture of the effect in normal metal thermoelectric loops. The thermoelectric effects in superconducting nanostructures may be comparable with that in systems of macroscopic size systems. At the same time, the masking effects inherent for macroscopic superconductors can be eliminated so that nanoscale structures are promising for studying the thermoelectric effects in superconductors.

#### Acknowledgments

The authors acknowledge support for this work by the grant of Swedish Royal Academy. V. L. G. and V. I. K. also acknowledge partial support for this work by the Russian National Foundation for Basic Research, grant No 03-02-17638.

#### APPENDIX A: TEMPERATURE DISTRIBUTION

The purpose of this section is to discuss the conditions when one can ascribe different temperatures to elections in two banks connected by a short bridge.

In recent years it has been demonstrated that the electronic temperature of a metal film may substantially differ from the lattice temperature of the dielectric substrate. For quasi-2D metallic nanostructures at low temperatures, there are two factors that are favorable for such a possibility. First, small electron-phonon collision rates prevent effective transfer of heat to the phonon system of the substrate. Second, the phonon heat conductivity of the substrate at small spatial scales turns out to be smaller than the electron heat conductivity within the film since the phonon mean free path is limited by the spatial inhomogeneity. Using the Wiedemann-Franz law, one estimates the electron heat current within the metal layer of a length  $L$  and cross-section  $S$  as

$$Q_{el} = \frac{T}{L} S D_{en} \quad (A1)$$

where  $T$  is the temperature difference,  $D_e$  is electron diffusivity, and  $n = (T = T_F) n$  is the concentration of quasiparticles participating in the heat transfer (where  $n$  is the total electron concentration while  $T_F$  is the Fermi energy). At the same time, the heat flux from the film to the substrate can be estimated as

$$Q_{\text{sub}} = \frac{SLnT}{\tau_{\text{eph}}} \quad (\text{A } 2)$$

where  $\tau_{\text{eph}}$  is electron-phonon relaxation time. From Eqs. (A 1), and (A 2), one sees that  $Q_{\text{el}} > Q_{\text{sub}}$  provided  $L^2 < l_e v_F \tau_{\text{eph}}$ .

It is also instructive to compare the electronic heat flux  $Q_{\text{el}}$  with the heat flux  $Q_{\text{ph}}$  supported by phonons in the substrate and "shunting" the electron flux. One easily obtains that  $Q_{\text{el}} > Q_{\text{ph}}$  provided

$$\frac{L \sin(w; l_{\text{ph}})}{d v_F l_e} \frac{T}{T_D} \frac{T_F^3}{T} < 1 \quad (\text{A } 3)$$

where  $T_D$  is the Debye temperature of the substrate,  $w$  is the width of the metal layer,  $d$  is the layer thickness,  $s$  is the sound velocity while  $l_e$  and  $l_{\text{ph}}$  are the mean free paths of electrons within the layer and phonons within the substrate, respectively. Since the electron heat conductivity dominates provided any of the aforementioned conditions holds, one concludes that at low temperatures the electron temperature is mainly controlled by electron heat conductivity of the metal structure.

Consider now a point ballistic bridge connecting to metal banks with different electronic temperatures. It follows from the above considerations that the temperature drop is concentrated mainly within the contact region. Indeed, for 3D geometry and a diffusive transport in the bulk, the temperature distribution in the banks near the bridge follows the same law as an electric potential distribution, that is the temperature drop is concentrated in the bridge. If the whole structure is made of a metal film of the same thickness and with the diffusive electron transport this statement holds only with a logarithmic accuracy because of the 2D character of electron diffusion. However if the thickness of the bridge region is much smaller than the thicknesses of the banks (that is if the configuration is a 3D-like one) the temperature drop is again completely restricted by the contact region. The same holds provided the electron transport within the contact and near-contact regions is ballistic. Indeed, it follows from the fact that under the Wiedemann-Franz law the temperature profile is similar to the electric potential profile while in 2D ballistic structures the potential drop is concentrated in the contact region.

It is expected that very large values of  $T$  can be realized in the point contact geometry. Indeed, one can apply for the heat flux the same arguments as for electric current through the point contact<sup>18</sup>, namely, that the relaxation processes for the electrons take place within the bulk of the sample at distances  $(\sim D_{\text{ee}})^{1/2}$ . Thus enormous values of temperature gradient and heat flux density do not lead to destruction of the bridge.

## 1. Electron heating

Let us consider the important practical question concerning the generation of the temperature gradient across the bridge. We have assumed above that the excitations within the one of the banks are heated as compared to the excitations in another one. Since we deal with superconductors, it excludes the Joule heating. On the other hand, microwave heating implies relatively large areas. In our opinion, the best way is to heat electrons on one of the banks using a tunnel S-I-N junction. The junction is formed by a normal film of area  $S_2$  put on the top of the superconducting bank (with a thin insulating layer). When the bias  $eV$  across the S-I-N junction is much larger than the superconductor energy gap, high-energy electrons tunnelling from N layer will relax mainly due to creation of electron-hole pairs within the superconducting layer. To have the electron temperature formed, one should have

$$S_2 > v_F l_{\text{ee}};$$

$l_{\text{ee}}$  being the electron-electron scattering time.

Now let us compare the thermal current from the heated superconducting layer to the substrate and the thermal current through the point contact to the "cold" bank. Assuming that the thickness of the superconducting layer forming the tunnel junction and the layer forming the point contact are the same, one finds that the thermal current through the contact dominates provided

$$S_2 L = w < l_e v_F \tau_{\text{eph}} \quad (\text{A } 4)$$

where  $L$  and  $w$  are the point contact length and width, respectively. If  $L \sim w$  one concludes, that this condition can hold since at low enough temperatures  $\tau_{\text{eph}} > l_{\text{ee}}$ . Correspondingly, in this case only a region with the area  $S_2$  (under the tunnel junction) is heated with respect to the rest of the device, the heat leak being due to thermal current through the point contact. Certainly, one should also assume that the area of the superconducting layer in the "cold" bank is large enough to ensure efficient heat withdrawal to its substrate. In this case one easily obtains

$$T \sim IV \frac{L T_F}{w d e n T} \quad (\text{A } 5)$$

where  $I$  is the current through the tunnel junction.

The main conclusion following from the considerations given above is that it is possible to have "point-like" electron heating restricted by the area  $\sim v_F l_{\text{ee}}$ . Its linear dimensions for realistic estimates can be as small as 3 nm. Correspondingly, if the inductance loop has macroscopic size this local heating (and corresponding local variation of the penetration length) is not expected to affect the temperature-dependent (or rather  $V$ -dependent) flux through the loop.

- 
- <sup>1</sup> V. L. Ginzburg, Zh. Eksp. Teor. Fiz. 14, 177 (1944).
  - <sup>2</sup> Yu. M. Galperin, V. L. Gurevich, V. I. Kozub, Sov. Phys. - JETP Letters, 17, 476 (1973); Yu. M. Galperin, V. L. Gurevich, V. I. Kozub, Sov. Phys. - JETP, 65, 1045 (1974)
  - <sup>3</sup> N. V. Zavaritskii, Pis'ma Zh. Eksp. Teor. Fiz. 20, 223 (1974) [JETP Lett. 20, 97 (1974)].
  - <sup>4</sup> D. G. Van Harlingen, J. C. Garland, Solid State Commun. 25, 419 (1978).
  - <sup>5</sup> D. J. Van Harlingen, D. F. Heide, and J. C. Garland, Phys. Rev. B 21, 1842 (1980).
  - <sup>6</sup> V. I. Kozub, Zh. Eksp. Teor. Fiz. 88, 1847 (1985) [Sov. Phys. JETP, 61, 1095 (1985)]
  - <sup>7</sup> C. M. Pegrum, A. M. Guenault, Phys. Letters, 59 A, 393 (1976)
  - <sup>8</sup> V. I. Kozub, Sov. Phys. - JETP, 47, 178 (1978).
  - <sup>9</sup> C. M. Falco, Phys. Rev. Lett. 39, 660 (1977).
  - <sup>10</sup> A. Schmid, G. Schon, Phys. Rev. Lett. 43, 793 (1979).
  - <sup>11</sup> A. L. Shelankov, Zh. Eksp. Teor. Fiz. 78, 2359 (1980) [Sov. Phys. - JETP, 51, 1186 (1980)].
  - <sup>12</sup> J. Clarke, B. R. Fjorvick, P. E. Lindelof, Phys. Rev. Lett. 43, 642 (1979).
  - <sup>13</sup> N. Artemenko, A. F. Volkov, Sov. Phys. - JETP, 43, 548 (1976)
  - <sup>14</sup> A. G. Aronov, Yu. M. Galperin, V. L. Gurevich and V. I. Kozub, in : Nonequilibrium superconductivity, ed. by V. M. Agranovich, A. A. M. Aradudin, North Holland, 1976.
  - <sup>15</sup> J. Clarke and M. Tinkham, Phys. Rev. Lett. 44, 106 (1980).
  - <sup>16</sup> A. L. Shelankov, Sov. Phys. Solid State 27, 965 (1985).
  - <sup>17</sup> J. Clarke, in : Nonequilibrium superconductivity, ed. by V. M. Agranovich, A. A. M. Aradudin, North Holland, 1976.
  - <sup>18</sup> I. O. Kulik, A. N. Omel'yanchuk, R. I. Shekhter, Solid State Commun. 23, 301 (1977)